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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

PHP21N06LT, PHB21N06LT PHD21N06LT

FEATURES

- 'Trench' technology
- Low on-state resistance
- Fast switching
- Logic level compatible



QUICK REFERENCE DATA



GENERAL DESCRIPTION

N-channel enhancement mode, logic level, field-effect power transistor in a plastic envelope using 'trench' technology.

Applications:-

- d.c. to d.c. converters
- switched mode power supplies

The PHP21N06LT is supplied in the SOT78 (TO220AB) conventional leaded package. The PHB21N06LT is supplied in the SOT404 (D²PAK) surface mounting package. The PHD21N06LT is supplied in the SOT428 (DPAK) surface mounting package.

PINNING

PIN	DESCRIPTION
1	gate
2	drain 1
3	source
tab	drain



SOT404 (D²PAK)

SOT428 (DPAK)





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DSS}	Drain-source voltage	T _i = 25 °C to 175°C	-	55	V
V _{DGR}	Drain-gate voltage	$T_{1} = 25 \text{ °C to } 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$	-	55	V
V _{GS}	Gate-source voltage		-	± 15	V
V _{GSM}	Pulsed gate-source voltage	T _i ≤ 150°C	-	± 20	V
I _D	Continuous drain current	T _{mb} = 25 °C	-	19	А
_		$T_{mb} = 100 \degree C$	-	13	А
I _{DM}	Pulsed drain current	$T_{mb} = 25 \degree C$	-	76	А
P _D	Total power dissipation	$T_{mb} = 25 \degree C$	-	56	W
T _j , T _{stg}	Operating junction and storage temperature		- 55	175	°C

¹ It is not possible to make connection to pin:2 of the SOT404 or SOT428 packages.

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AVALANCHE ENERGY LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
7.0		Unclamped inductive load, $I_{AS} = 9.7 \text{ A}$; $t_p = 100 \ \mu\text{s}$; T_j prior to avalanche = 25°C; $V_{DD} \le 25 \text{ V}$; $R_{GS} = 50 \ \Omega$; $V_{GS} = 5 \text{ V}$; refer to fig:15	-	34	mJ
I _{AS}	Peak non-repetitive avalanche current	°	-	19	A

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	2.7	K/W
R _{th j-a}	Thermal resistance junction to ambient	SOT78 package, in free air SOT428 and SOT404 package, pcb mounted, minimum footprint	60 50	-	K/W K/W

ELECTRICAL CHARACTERISTICS

 $T_i = 25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; \text{ I}_{D} = 0.25 \text{ mA};$ $T_{i} = -55^{\circ}\text{C}$	55 50	-	-	V V
$V_{GS(TO)}$	Gate threshold voltage	$V_{DS} = V_{GS}; I_{D} = 1 \text{ mA}$	1.0 0.5	1.5 -	2.0	V V
$R_{DS(ON)}$	Drain-source on-state resistance	$T_{j} = 175^{\circ}C$ $T_{j} = -55^{\circ}C$ $V_{GS} = 10 \text{ V}; \text{ I}_{D} = 10 \text{ A}$ $V_{GS} = 5 \text{ V}; \text{ I}_{D} = 10 \text{ A}$		- 55 60	2.3 70 75	V mΩ mΩ
g _{fs} I _{GSS} I _{DSS}	Forward transconductance Gate source leakage current Zero gate voltage drain current	$T_{j} = 175^{\circ}C$ $V_{DS} = 25 \text{ V}; I_{D} = 10 \text{ A}$ $V_{GS} = \pm 5 \text{ V}; V_{DS} = 0 \text{ V}$ $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V};$ $T_{j} = 175^{\circ}C$	- 5 - - -	- 13 10 0.05 -	158 - 100 10 500	mΩ S nA μA μA
$\begin{matrix} Q_{g(tot)} \\ Q_{gs} \\ Q_{gd} \end{matrix}$	Total gate charge Gate-source charge Gate-drain (Miller) charge	$I_D = 20 \text{ A}; V_{DD} = 44 \text{ V}; V_{GS} = 5 \text{ V}$	- - -	9.4 2.2 5.4	- - -	nC nC nC
t _{d on} t _r t _{d off} t _f	Turn-on delay time Turn-on rise time Turn-off delay time Turn-off fall time		- - -	7 88 25 25	15 120 40 45	ns ns ns ns
L _d L _d	Internal drain inductance Internal drain inductance	Measured from tab to centre of die Measured from drain lead to centre of die (SOT78 package only)	-	3.5 4.5	-	nH nH
L _s	Internal source inductance	Measured from source lead to source bond pad		7.5	-	nH
$\begin{array}{c} C_{iss} \\ C_{oss} \\ C_{rss} \end{array}$	Input capacitance Output capacitance Feedback capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz$		466 95 71	650 135 85	pF pF pF

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REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

 $T_i = 25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _S	Continuous source current (body diode)		-	-	19	A
I _{SM}	Pulsed source current (body diode)		-	-	76	A
V_{SD}	Diode forward voltage	I _F = 20 A; V _{GS} = 0 V	-	1.2	1.5	V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$ I_F = 20 \text{ A}; -dI_F/dt = 100 \text{ A}/\mu\text{s}; \\ V_{GS} = 0 \text{ V}; \text{ V}_R = 30 \text{ V} $	-	43 94	-	ns nC









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MECHANICAL DATA



Notes

- 1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
- 2. Refer to mounting instructions for SOT78 (TO220AB) package.
- 3. Epoxy meets UL94 V0 at 1/8".

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MECHANICAL DATA



Notes

1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.

- 2. Refer to SMD Footprint Design and Soldering Guidelines, Data Handbook SC18.
- 3. Epoxy meets UL94 V0 at 1/8".

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MOUNTING INSTRUCTIONS



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MECHANICAL DATA



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MOUNTING INSTRUCTIONS

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.
••	ation is given, it is advisory and does not form part of the specification.
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